

In the Claims

Applicant has submitted a new complete claim set.

Please cancel claims 2, 4, 6, 11-12, 15, 19, 55, 63-59 without prejudice or disclaimer.

1. An article comprising:
an electrical crossbar array comprising at least two crossed wires, at least one of which is a nanoscopic wire.
2. Canceled
3. An article as in claim 2, wherein the at least two wires are in electrical contact with each other.
4. Canceled
5. An article as in claim 1, wherein the at least two wires are not in contact with each other.
6. Canceled
7. An article as in claim 1, wherein the at least two wires comprise a first wire disposed adjacent a second wire at a junction.
8. An article as in claim 7, wherein the first wire is positioned on a substrate.
9. An article as in claim 8, wherein the first wire is positioned intermediate the substrate and the second wire.
10. An article as in claim 9, wherein the second wire is supported above the first wire, relative to the substrate.

11-12 Canceled

13. An article as in claim 7, wherein the second wire has sufficient stiffness to remain free of contact with the first wire.

14. An article as in claim 13, wherein the second wire has a sufficient Young's modulus, such that the second wire is capable of deformable van der Waals contact with the first wire at the junction, upon exposure to a stimulus.

15. Canceled

16. An article as in claim 1, wherein the crossbar array comprises a first set and second set of at least two parallel wires.

17. An article as in claim 16, wherein the first set of parallel wires is perpendicular to the second set of parallel wires.

18. An article as in claim 16, wherein the second set of wires is disposed adjacent the first set of wires at a plurality of junctions.

19. Canceled

20. An article as in claim 1, further comprising a contact electrode in electrical contact with at least one of the wires.

21. An article as in claim 20, wherein the at least one wire is attached to the contact electrode.

22. An article as in claim 20, wherein the at least one wire is covalently attached to the contact electrode.

23. An article as in claim 1, wherein each of the at least two wires is in electrical contact with a different contact electrode.
24. A method comprising:
forming a nanoscopic wire on a surface in a pattern dictated by chemically patterned surface.
25. A method as in claim 24, wherein the patterned surface includes a first portion of a first chemical functionality adjacent a second portion of a second, different chemical functionality.
26. A method as in claim 25, wherein at least one of the first portion and the second portion is defined by a self-assembled monolayer.
27. A method as in claim 24, wherein the nanoscopic wire is a pre-formed wire, the method comprising applying the pre-formed nanoscopic wire to the surface in the pattern.
28. A method as in claim 24, comprising growing the nanoscopic wire on the surface in the pattern.
29. A method as in claim 24, wherein the pattern comprises a plurality of catalytic colloid sites.
30. A method as in claim 24, wherein the pattern comprises a micro-phase separated block copolymer structure.
31. A method comprising:
growing a nanoscopic wire in the presence of an electric field of intensity sufficient to orient the growth of the wire.

32. A method as in claim 31, comprising growing the nanoscopic wire via CVD.
33. A method as in claim 31, comprising providing a catalytic site, creating the electric field oriented in a predetermined direction relative to the catalytic site, and growing the nanoscopic wire catalytically from the site in the predetermined direction.
34. A method comprising:
forming a nanoscopic wire on a surface in a pattern dictated by a mechanically patterned surface.
35. A method as in claim 34, wherein the step of forming comprises inscribing a trench in the surface.
36. A method as in claim 35, wherein the nanoscopic wire is formed in the trench.
37. A method as in claim 34, wherein the step of forming comprises providing an article having a plurality of indentations and protrusions, and positioning the plurality of protrusions in contact with the surface so as to form cavities defined by the surface and the plurality of indentations.
38. A method as in claim 37, wherein the cavities comprise capillaries.
39. A method comprising:
forming a nanoscopic wire on a surface in a pattern dictated by gas flow.
40. A method as in claim 39, wherein the gas flow comprises reactants for the nanoscopic wire.
41. A method comprising:
providing a crossbar array comprising at least two wires in crossbar array orientation, the

wires being free of contact with each other; and
bringing the wires into contact with each other.

42. A method as in claim 41, wherein the crossbar array includes at least one nanoscopic wire.

43. A method as in claim 41, wherein the at least two wires comprise a first wire disposed adjacent a second wire at a junction.

44. A method as in claim 43, wherein the wires are brought into electrical contact with each other at the junction.

45. A method as in claim 43, wherein the wires are brought into van der Waals contact with each other at the junction.

46. A method as in claim 45, wherein the step of bringing the wires into contact with each other comprises deforming the second wire.

47. A method as in claim 43, wherein the first and second wires are brought into contact by applying a stimulus to at least the second wire.

48. A method as in claim 47, wherein the stimulus comprises biasing the first and second wires with opposite polarity.

49. A method as in claim 47, wherein the first and second wires maintain contact upon removal of the stimulus.

50. A method as in claim 43, further comprising releasing the wires from contact with each other.

51. A method as in claim 50, wherein the step of releasing comprises applying a stimulus to at least the second wire.
52. A method as in claim 51, wherein the stimulus comprises biasing the first and second wires with the same polarity.
53. A method as in claim 41, further comprising releasing the wires from contact with each other.
54. A method as in claim 53, wherein each of the steps of bringing the wires into contact and releasing the wires from contact comprises a switching step.
55. Canceled
56. An article comprising:
an electrical crossbar array comprising at least two crossed wires defining a memory element able to be switched between at least two readable states, the device free of means addressing the memory element to effect switching of the memory element between the at least two states.
57. An article comprising:
an electrical crossbar array comprising at least two crossed wires defining a memory element able to be switched between at least two readable states, the device free of auxiliary circuitry defining the memory element.
58. An article as in claim 57, wherein the memory element comprises a junction of the two crossed wires.
59. An article as in claim 57, wherein the auxiliary circuitry includes transistors and capacitors.

60. A method comprising:
switching a memory element of a crossbar array between “on” and “off” states by alternatively biasing, at similar and opposite polarity, wires that cross in the array to define the element.
61. A method as in claim 60, comprising biasing the wires that cross to form the element from locations remote from the element.
62. A method as in claim 60, comprising switching the element between “on” and “off” states by bringing wires that cross in the array to form the memory element alternately into contact with each other and removing them from contact with each other.

63-89 Canceled